



Product Summary

BV _{DSS}	R _{DS(ON)}	Ι _D T _A = +25°C
100V	6.0Ω @ V _{GS} = 10V	0.17A

Description and Applications

These N-Channel enhancement mode field effect transistors are produced using DIODES proprietary, high density, uses advanced trench technology. These products have been designed to minimize on-state resistance while provide rugged, reliable, and fast switching performance. These products are particularly suited for low voltage, low current applications such as:

- Small Servo Motor Control
- Power MOSFET Gate Drivers
- Switching Applications

N-CHANNEL ENHANCEMENT MODE MOSFET

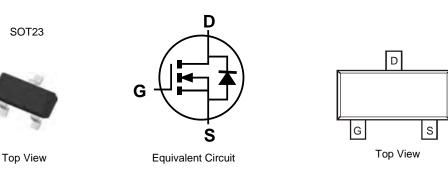
Features and Benefits

- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- High Drain-Source Voltage Rating
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
 The BSS123Q is suitable for automotive applications
- The BSS123Q is suitable for automotive applications requiring specific change control; these parts are AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Alloy 42 Leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208⁽³⁾
- Terminal Connections: See Diagram
- Weight: 0.008 grams (Approximate)



Ordering Information (Note 4)

Part Number	Qualification	Case	Packaging
BSS123-7-F	Commercial	SOT23	3,000 / Tape & Reel
BSS123Q-13	Automotive	SOT23	10,000 / Tape & Reel
BSS123Q-7	Automotive	SOT23	3,000 / Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



K23 = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: C = 2015) M = Month (ex: 9 = September)

Date Code Key

Year	2006	2007	2008	2009	2010	2011	2012	2013	2014	2015	2016	2017
Code	Т	U	V	W	Х	Y	Z	А	В	С	D	E
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage		V _{DSS}	100	V
Gate-Source Voltage	Continuous	V _{GSS}	±20	V
	Continuous	Ι _D	170	~^
Continuous Drain Current (Note 5) $V_{GS} = 10V$	Pulsed	I _{DM}	680	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Max	Unit
Power Dissipation (Note 5)	PD	300	mW
Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ (Note 5)	R _{θJA}	417	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

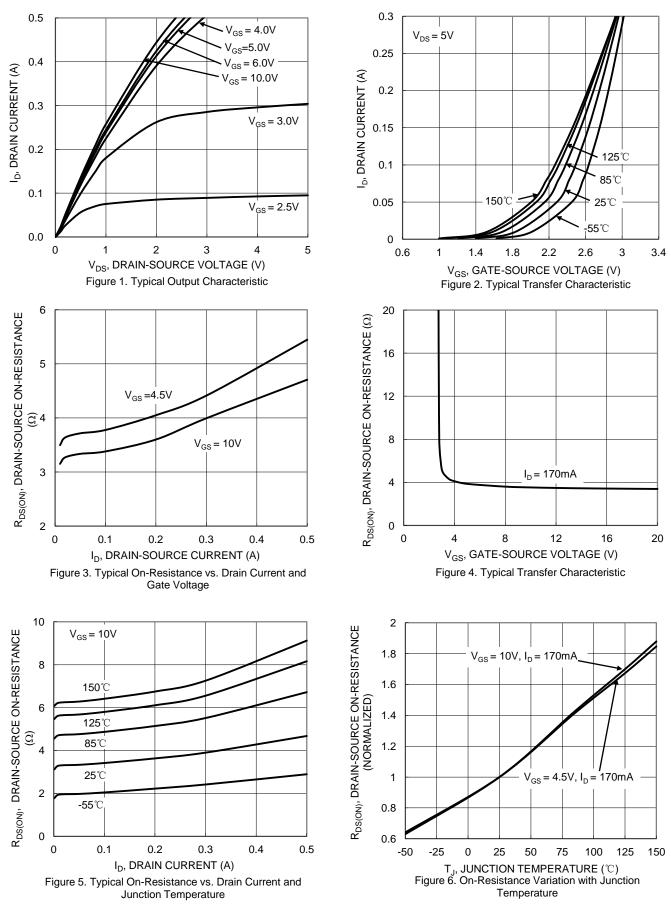
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 6)							
Drain-Source Breakdown Voltage	BV _{DSS}	100	-	-	V	$V_{GS} = 0V, I_D = 250 \mu A$	
		-	-	0.1	μA	$V_{DS} = 100V, V_{GS} = 0V$	
Zero Gate Voltage Drain Current	I _{DSS}	-	-	30	μA	V _{DS} = 100V, V _{GS} = 0V @ T _A = +150°C (Note 7)	
		-	-	10	nA	$V_{DS} = 20V, V_{GS} = 0V$	
Gate-Source Leakage, Forward	I _{GSSF}	-	-	50	nA	$V_{GS} = 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 6)						·	
Gate Threshold Voltage	V _{GS(TH)}	0.8	1.4	2.0	V	$V_{DS} = V_{GS}, I_D = 1mA$	
Static Drain-Source On-Resistance	R _{DS(ON)}	-	-	6.0	Ω	$V_{GS} = 10V, I_D = 0.17A$	
Static Drain-Source On-Resistance		-	-	10		$V_{GS} = 4.5V, I_D = 0.17A$	
Forward Transfer Admittance	g _{FS}	80	370	-	ms	V _{DS} =10V, I _D = 0.17A, f = 1.0KHz	
Diode Forward Voltage	V _{SD}	-	0.84	1.3	V	V _{GS} = 0V, I _S = 0.34A	
DYNAMIC CHARACTERISTICS (Note 7)						·	
Input Capacitance	Ciss	-	22	60			
Output Capacitance	Coss	-	3.5	15	pF	$V_{DS} = 25V, V_{GS} = 0V, f = 1.0MHz$	
Reverse Transfer Capacitance	C _{rss}	-	2.0	6			
SWITCHING CHARACTERISTICS (Note 7)							
Turn-On Delay Time	t _{D(ON)}	-	-	8	ns		
Turn-On Rise Time	t _R	-	-	8	ns	V _{GS} = 10V, V _{DD} = 30V,	
Turn-Off Delay Time	t _{D(OFF)}	-	-	13	ns	$I_D = 0.28A, R_{GEN} = 50\Omega$	
Turn-Off Fall Time	t _F	-	-	16	ns		

Notes:

5. Part mounted on FR-4 board with recommended pad layout, which can be found on our website at http://www.diodes.com/package-outlines.html. 6. Short duration pulse test used to minimize self-heating effect.
 7. Guaranteed by design. Not subject to production testing.

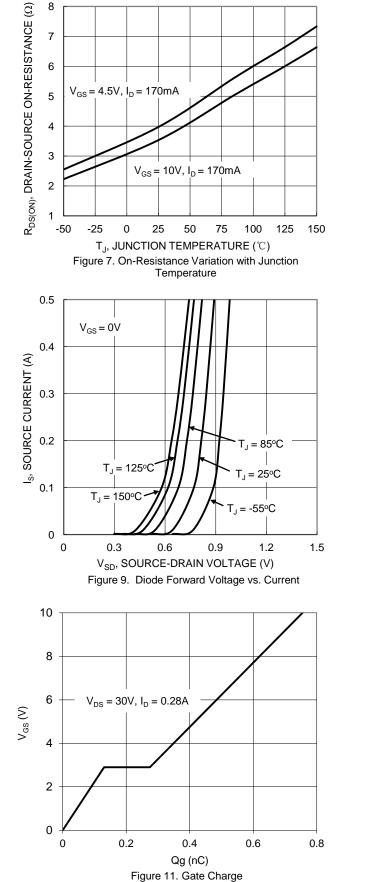


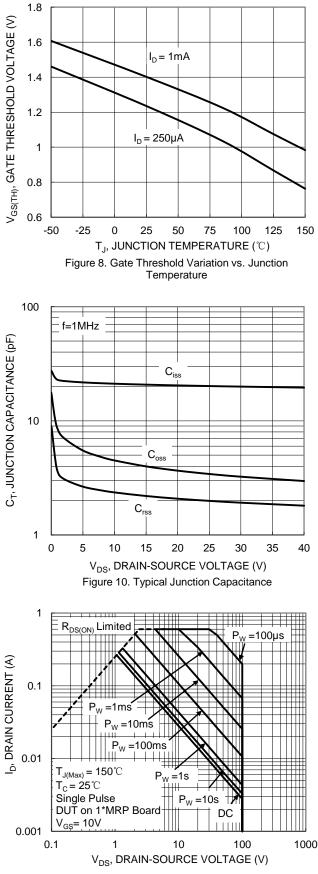


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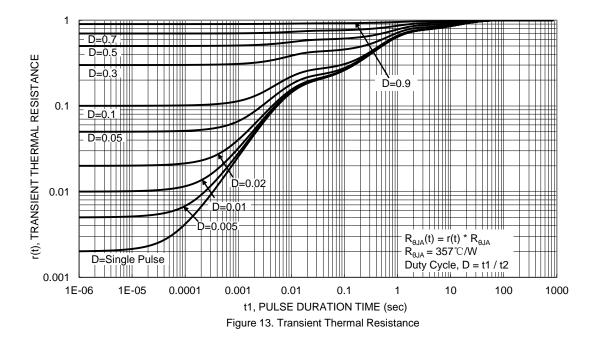
BSS123









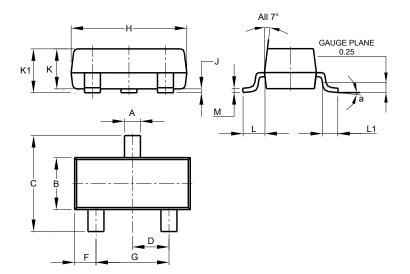




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

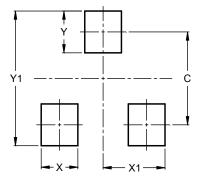




SOT23								
Dim	Min	Max	Тур					
Α	0.37	0.51	0.40					
В	1.20	1.40	1.30					
С	2.30	2.50	2.40					
D	0.89	1.03	0.915					
F	0.45	0.60	0.535					
G	1.78	2.05	1.83					
Н	2.80	3.00	2.90					
J	0.013	0.10	0.05					
κ	0.890	1.00	0.975					
K1	0.903	1.10	1.025					
L	0.45	0.61	0.55					
L1	0.25	0.55	0.40					
М	0.085	0.150	0.110					
а	0°	8°						
All Dimensions in mm								

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23

Dimensions	Value (in mm)			
С	2.0			
Х	0.8			
X1	1.35			
Y	0.9			
Y1	2.9			



BSS123

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